



60V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8 (Type UX)

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C		
	16mΩ @ V _{GS} = 10V	38A		
60V	26mΩ @ V _{GS} = 4.5V	29.8A		

Features and Benefits

- 100% Unclamped Inductive Switching, Test in Production Ensures More Reliable And Robust End Application
- Low R_{DS(ON)} Ensures On-State Losses are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

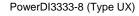
Description and Applications

This MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

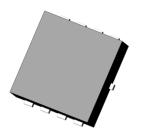
- Motor Control
- DC-DC Converters
- Power Management

Mechanical Data

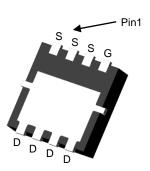
- Case: PowerDI[®]3333-8 (Type UX)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.072 grams (Approximate)



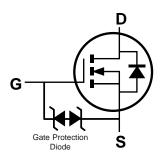




Top View



Bottom View



Internal Schematic

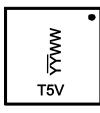
Ordering Information (Note 4)

Part Number	Case	Packaging		
DMT615MLFV-7	PowerDI3333-8 (Type UX)	2,000/Tape & Reel		
DMT615MLFV-13	PowerDI3333-8 (Type UX)	3,000/Tape & Reel		

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



T5V= Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 18 = 2018)

WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V_{DSS}	60	V	
Gate-Source Voltage		V _{GSS}	±20	V
	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	8.5 6.8	А
Continuous Drain Current (Note 5) V _{GS} = 10V	$T_C = +25$ °C $T_C = +70$ °C	I _D	38 30	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	60	Α	
Maximum Continuous Body Diode Forward Current (Note 5)	Is	1.85	Α	
Avalanche Current, L = 0.1mH	I _{AS}	19	Α	
Avalanche Energy, L = 0.1mH		Eas	18.05	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

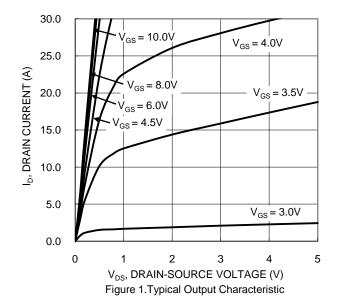
Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P_{D}	1.76	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta JA}$	71	°C/W
Total Power Dissipation (Note 6)	P _D	34.72	W
Thermal Resistance, Junction to Case (Note 6)	$R_{\theta JC}$	3.6	°C/W
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C

Electrical Characteristics (@ $T_A = \pm 25$ °C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	60		_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	1	1	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance		_	12.2	16	mΩ	$V_{GS} = 10V, I_D = 10A$	
Static Diani-Source On-Resistance	R _{DS(ON)}	_	19.5	26		$V_{GS} = 4.5V, I_D = 6A$	
Diode Forward Voltage	V _{SD}	_	0.7	1.2	V	$V_{GS} = 0V$, $I_S = 1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	_	1039	_	pF	$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss		233	_	рF		
Reverse Transfer Capacitance	C _{rss}		19		рF		
Gate Resistance	R _G	_	1.48	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Q_{G}		7.8	_	nC		
Total Gate Charge (V _{GS} = 10V)	Q_{G}	_	15.5	_	nC	V 20V I 40A	
Gate-Source Charge	Q _{GS}	_	2.3	_	nC	$V_{DS} = 30V, I_{D} = 10A$	
Gate-Drain Charge	Q_{GD}	_	3.5	_	nC	1	
Turn-On Delay Time	t _{D(ON)}	_	4.5	_	ns		
Turn-On Rise Time	t _R	_	5.6	_	ns	$V_{GS} = 10V, V_{DS} = 30V,$ $R_G = 6\Omega, I_D = 10A$	
Turn-Off Delay Time	t _{D(OFF)}	_	13.8	_	ns		
Turn-Off Fall Time	t _F	_	5	_	ns		
Body Diode Reverse Recovery Time	t _{RR}	_	20.6	_	ns	I _F = 10A, di/dt = 100A/μs	
Body Diode Reverse Recovery Charge	Q _{RR}	_	11.4	_	nC		

 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad).
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing. Notes:





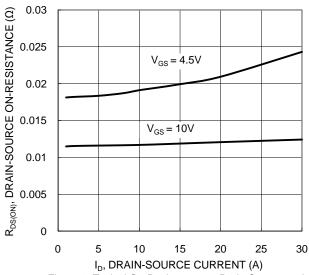


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

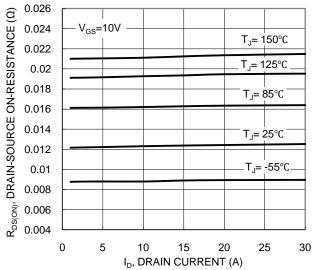
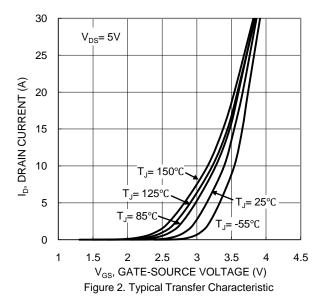
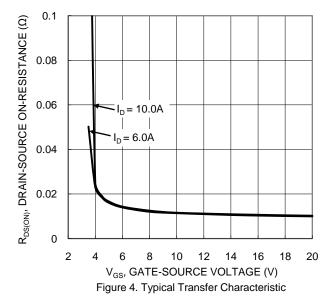


Figure 5. Typical On-Resistance vs. Drain Current and Temperature





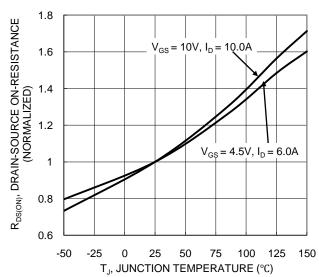


Figure 6. On-Resistance Variation with Temperature



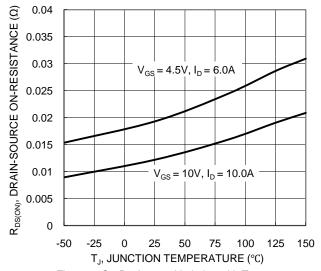
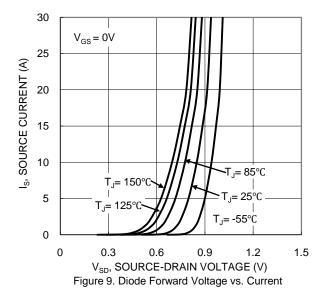
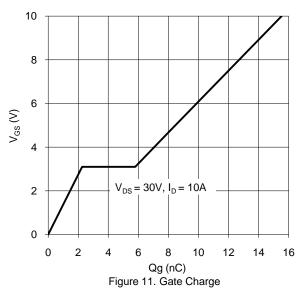
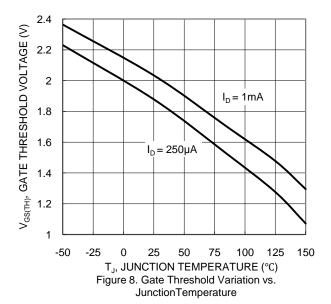
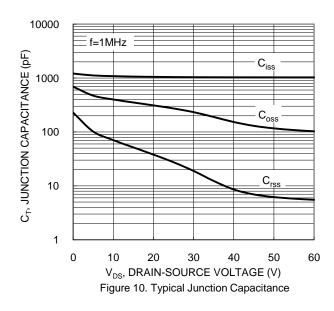


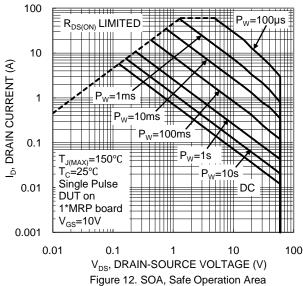
Figure 7. On-Resistance Variation with Temperature













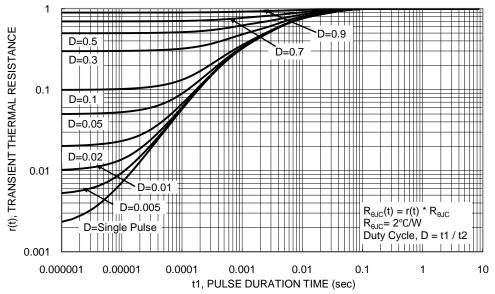


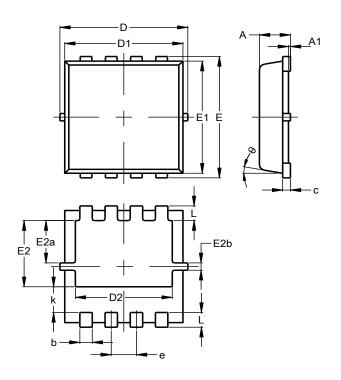
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UX)

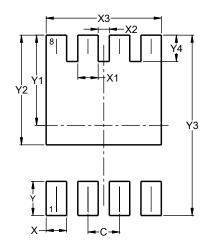


PowerDI3333-8 (Type UX)					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05			
b	0.25	0.40	0.32		
С	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
Е	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E2a	0.95	1.35	1.15		
E2b	0.10	0.30	0.20		
е	0.65 BSC				
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UX)



Dimensions	Value (in mm)
С	0.650
X	0.420
X1	0.420
X2	0.230
Х3	2.370
Υ	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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